

SCHOTTKY BARRIER RECTIFIER

VOLTAGE RANGE: 20 --- 200 V
CURRENT: 5.0A

FEATURES

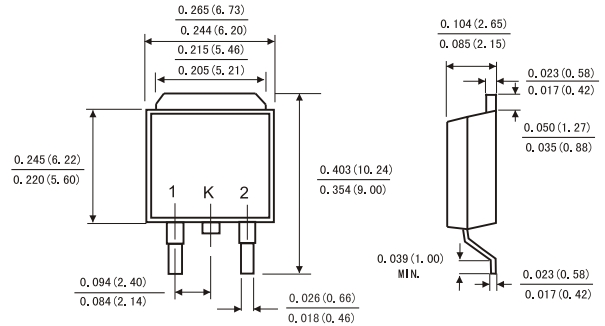
- ◇ Metal-semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-0

MECHANICAL DATA

- ◇ Case: JEDEC TO-252, molded plastic
- ◇ Terminals: Axial lead, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 0.4 grams
- ◇ Mounting position: Any

TO-252

(DPAK)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

| | Symbols | MBR 520 | MBR 530 | MBR 540 | MBR 550 | MBR 560 | MBR 580 | MBR 5A0 | MBR 5150 | MBR 5200 | Units |
|---|------------------|-------------|---------|---------|---------|---------|---------|---------|----------|----------|-------|
| Maximum repetitive peak reverse voltage | V _{RRM} | 20 | 30 | 40 | 50 | 60 | 80 | 100 | 150 | 200 | Volts |
| Maximum RMS voltage | V _{RMS} | 14 | 21 | 28 | 35 | 42 | 57 | 71 | 105 | 140 | Volts |
| Maximum DC blocking voltage | V _{DC} | 20 | 30 | 40 | 50 | 60 | 80 | 100 | 150 | 200 | Volts |
| Maximum average forward rectified current 0.375" (9.5mm) lead length (see fig. 1) | I(AV) | 5.0 | | | | | | | | | Amps |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated T _J) | I _{FSM} | 150.0 | | | | | | | | | Amps |
| Maximum instantaneous forward voltage at 5.0 A (Note 1) | V _F | 0.55 | | 0.70 | | 0.85 | | 0.90 | | 0.95 | Volts |
| Maximum instantaneous reverse current at rated DC blocking voltage (Note 1) | I _R | 0.2 | | | | | | | | | mA |
| | | 50 | | | 25 | | | | | | |
| Typical junction capacitance (Note 3) | C _J | 500 | | | 400 | | | | | | pF |
| Typical thermal resistance (Note 2) | R _{θJA} | 25.0 | | | | | | | | | °C/W |
| | R _{θJL} | 8.0 | | | | | | | | | |
| Operating junction temperature range | T _J | -65 to +150 | | | | | | | | | °C |
| Storage temperature range | T _{STG} | -65 to +150 | | | | | | | | | °C |

- NOTE: 1. Pulse test: 300us pulse width, 1% duty cycle.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Thermal resistance junction to ambient

FIG.1-FORWARD CURRENT DERATING CURVE

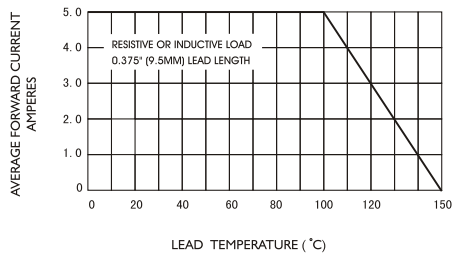


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

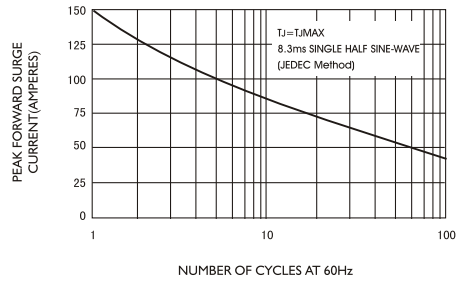


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

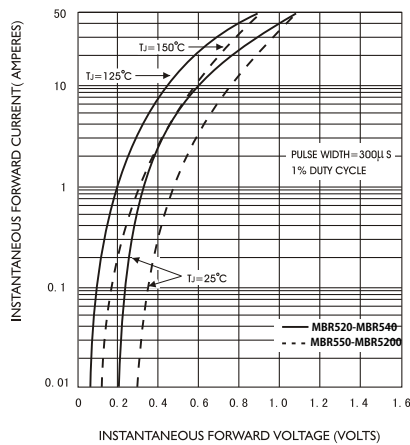


FIG.4-TYPICAL REVERSE CHARACTERISTICS

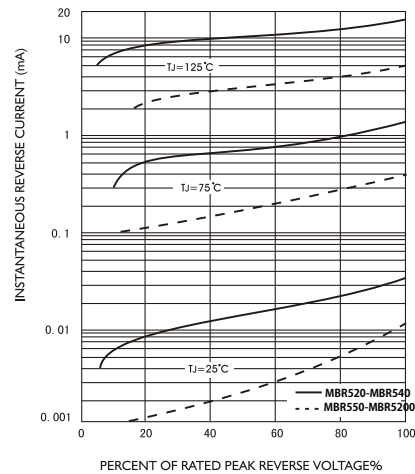


FIG.5-TYPICAL JUNCTION CAPACITANCE

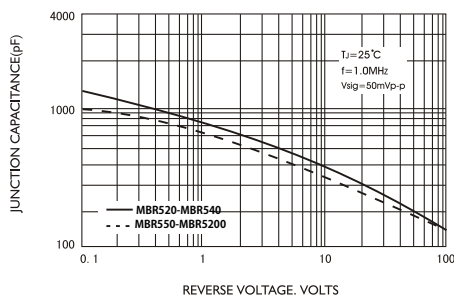


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

